

Dual P-Channel 20-V (D-S) MOSFET

| PRODUCT SUMMARY | | |
|---------------------|------------------------------------|--------------------|
| V _{DS} (V) | R _{DS(on)} (Ω) | I _D (A) |
| - 20 | 0.110 at V _{GS} = - 4.5 V | - 2.5 |
| | 0.145 at V _{GS} = - 2.5 V | - 2.0 |
| | 0.220 at V _{GS} = - 1.8 V | - 1.0 |

FEATURES

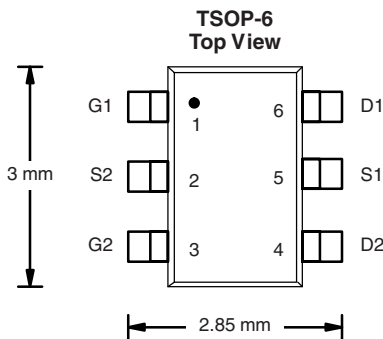
- Halogen free According to IEC 61249-2-21 Definition
- TrenchFET® Power MOSFET
- Symmetrical Dual P-Channel
- Compliant to RoHS Directive 2002/95/EC



RoHS
COMPLIANT
HALOGEN
FREE
Available

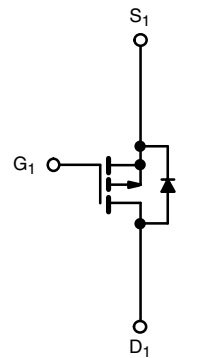
APPLICATIONS

- Battery Switch for Portable Devices
- Computers
 - Bus Switch
 - Load Switch

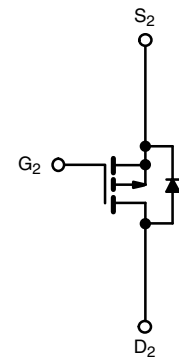


Ordering Information: Si3983DV-T1-E3 (Lead (Pb)-free)
Si3983DV-T1-GE3 (Lead (Pb)-free and Halogen free)

Marking Code: MDxxx



P-Channel MOSFET



P-Channel MOSFET

| ABSOLUTE MAXIMUM RATINGS T _A = 25 °C, unless otherwise noted | | | | |
|---|-----------------------------------|------------------------|--------------|-------|
| Parameter | Symbol | 5 s | Steady State | Unit |
| Drain-Source Voltage | V _{DS} | - 20 | | V |
| Gate-Source Voltage | V _{GS} | ± 8 | | |
| Continuous Drain Current (T _J = 150 °C) ^a | I _D | T _A = 25 °C | - 2.5 | - 2.1 |
| | | T _A = 70 °C | - 2.0 | - 1.7 |
| Pulsed Drain Current | I _{DM} | - 8 | | A |
| Continuous Source Current (Diode Conduction) ^a | I _S | - 1.05 | - 0.75 | |
| Maximum Power Dissipation ^a | P _D | T _A = 25 °C | 1.15 | 0.83 |
| | | T _A = 70 °C | 0.73 | 0.53 |
| Operating Junction and Storage Temperature Range | T _J , T _{stg} | - 55 to 150 | | °C |

| THERMAL RESISTANCE RATINGS | | | | | |
|--|-------------------|--------------|---------|------|------|
| Parameter | Symbol | Typical | Maximum | Unit | |
| Maximum Junction-to-Ambient ^a | R _{thJA} | t ≤ 5 s | 93 | 110 | °C/W |
| | | Steady State | 130 | 150 | |
| Maximum Junction-to-Foot (Drain) | R _{thJF} | 90 | 90 | | |

Notes:

a. Surface Mounted on 1" x 1" FR4 board.

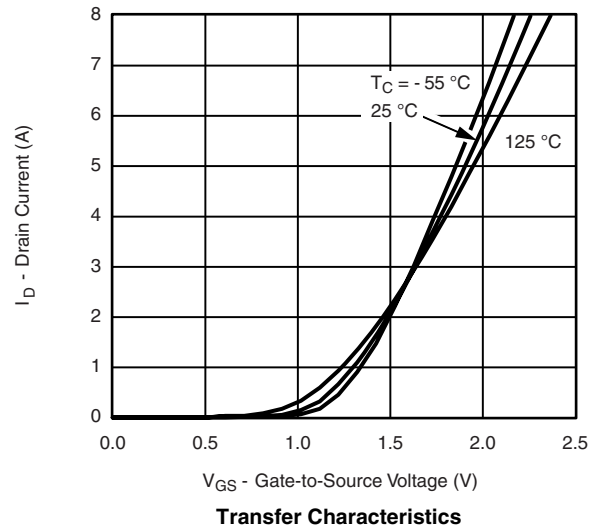
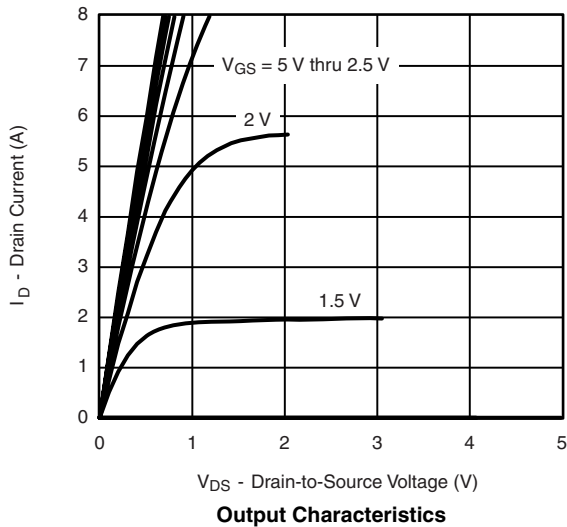
| SPECIFICATIONS $T_J = 25\text{ }^\circ\text{C}$, unless otherwise noted | | | | | | |
|--|--------------|--|-------|-------|-----------|---------------|
| Parameter | Symbol | Test Conditions | Min. | Typ. | Max. | Unit |
| Static | | | | | | |
| Gate Threshold Voltage | $V_{GS(th)}$ | $V_{DS} = V_{GS}, I_D = -250\text{ }\mu\text{A}$ | -0.40 | | -1.1 | V |
| Gate-Body Leakage | I_{GSS} | $V_{DS} = 0\text{ V}, V_{GS} = \pm 8\text{ V}$ | | | ± 100 | nA |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}$ | | | -1 | μA |
| | | $V_{DS} = -20\text{ V}, V_{GS} = 0\text{ V}, T_J = 85\text{ }^\circ\text{C}$ | | | -10 | |
| On-State Drain Current ^a | $I_{D(on)}$ | $V_{DS} = -5\text{ V}, V_{GS} = -4.5\text{ V}$ | -5 | | | A |
| Drain-Source On-State Resistance ^a | $R_{DS(on)}$ | $V_{GS} = -4.5\text{ V}, I_D = -2.5\text{ A}$ | | 0.086 | 0.110 | Ω |
| | | $V_{GS} = -2.5\text{ V}, I_D = -2.0\text{ A}$ | | 0.116 | 0.145 | |
| | | $V_{GS} = -1.8\text{ V}, I_D = -1.0\text{ A}$ | | 0.170 | 0.220 | |
| Forward Transconductance ^a | g_{fs} | $V_{DS} = -5\text{ V}, I_D = -2.5\text{ A}$ | | 6 | | S |
| Diode Forward Voltage ^a | V_{SD} | $I_S = -1.05\text{ A}, V_{GS} = 0\text{ V}$ | | -0.8 | -1.1 | V |
| Dynamic^b | | | | | | |
| Total Gate Charge | Q_g | $V_{DS} = -10\text{ V}, V_{GS} = -4.5\text{ V}, I_D = -2.5\text{ A}$ | | 5 | 7.5 | nC |
| Gate-Source Charge | Q_{gs} | | 0.68 | | | |
| Gate-Drain Charge | Q_{gd} | | 1.30 | | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{DD} = -10\text{ V}, R_L = 10\text{ }\Omega$ $I_D \cong -1\text{ A}, V_{GEN} = -4.5\text{ V}, R_g = 6\text{ }\Omega$ | | 28 | 45 | ns |
| Rise Time | t_r | | 55 | 85 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | 55 | 85 | | |
| Fall Time | t_f | | 32 | 50 | | |
| Source-Drain Reverse Recovery Time | t_{rr} | $I_F = -1.05\text{ A}, di/dt = 100\text{ A}/\mu\text{s}$ | | 25 | 40 | |

Notes:

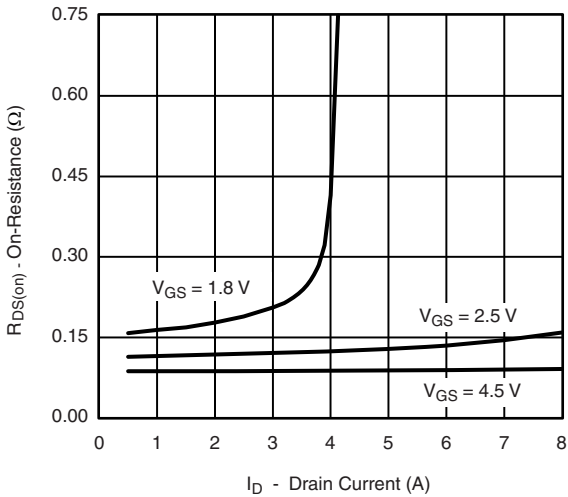
- a. Pulse test; pulse width $\leq 300\text{ }\mu\text{s}$, duty cycle $\leq 2\%$.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

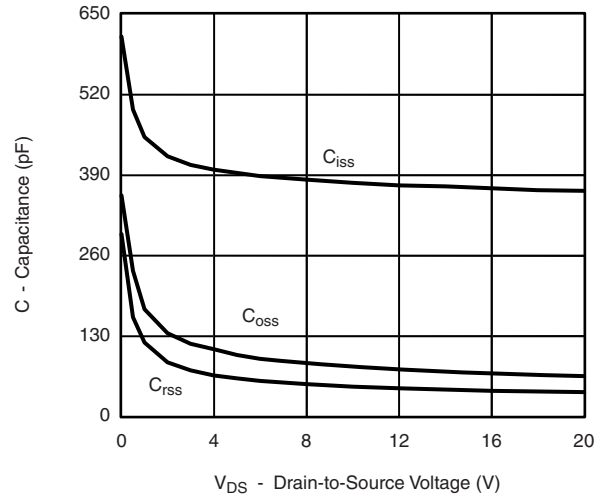
TYPICAL CHARACTERISTICS $25\text{ }^\circ\text{C}$, unless otherwise noted



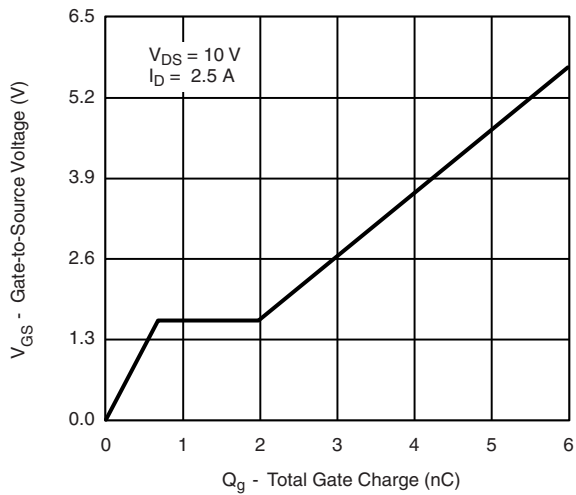
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



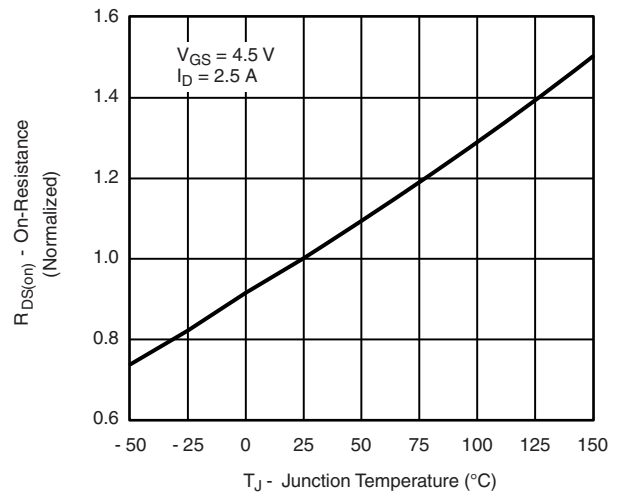
On-Resistance vs. Drain Current



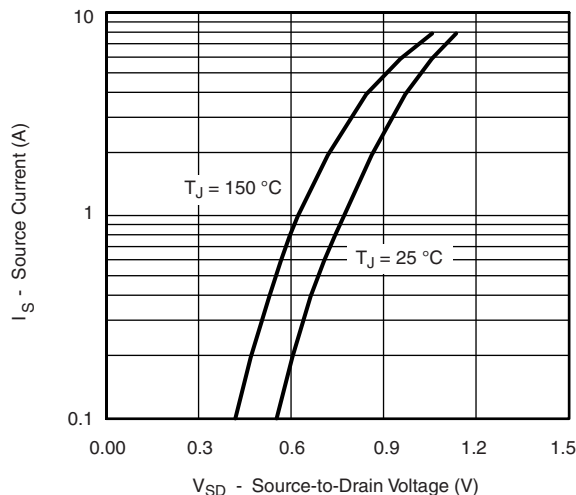
Capacitance



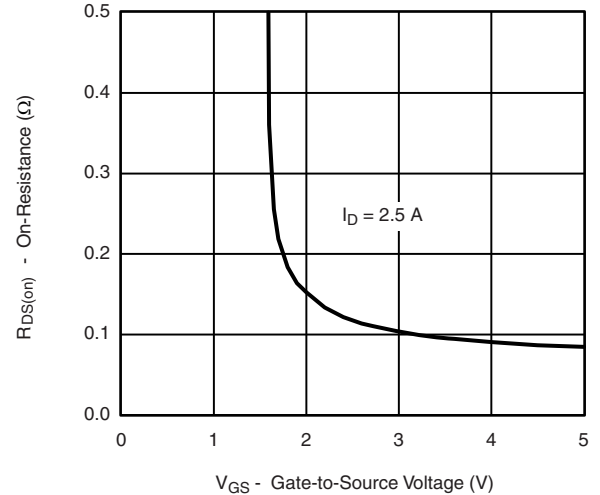
Gate Charge



On-Resistance vs. Junction Temperature

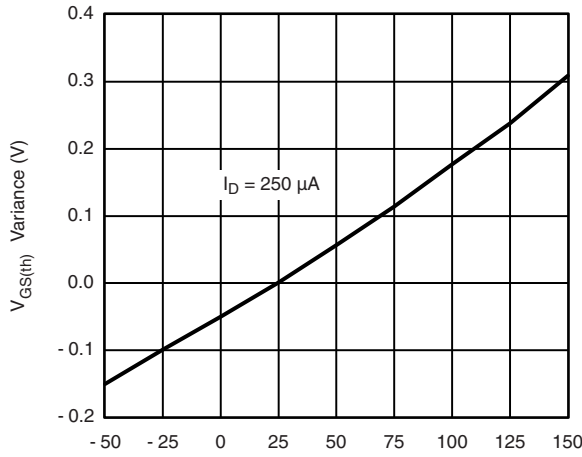


Source-Drain Diode Forward Voltage

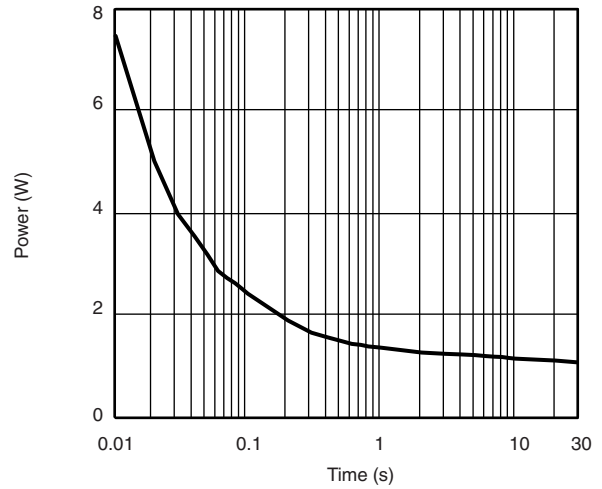


On-Resistance vs. Gate-to-Source Voltage

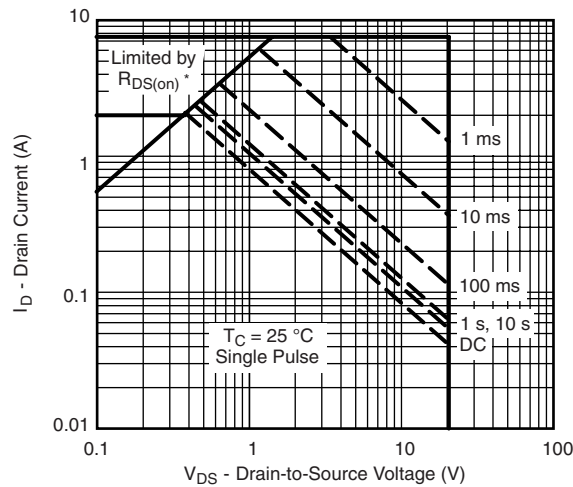
TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



T_J - Temperature (°C)
Threshold Voltage

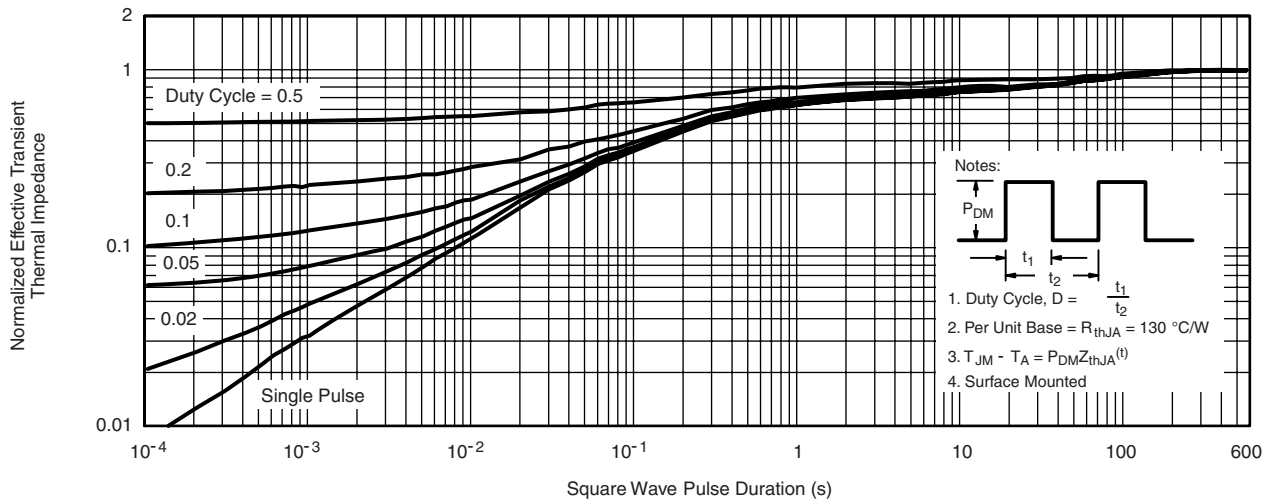


Single Pulse Power, Junction-to-Ambient



* V_{GS} > minimum V_{GS} at which R_{DS(on)} is specified

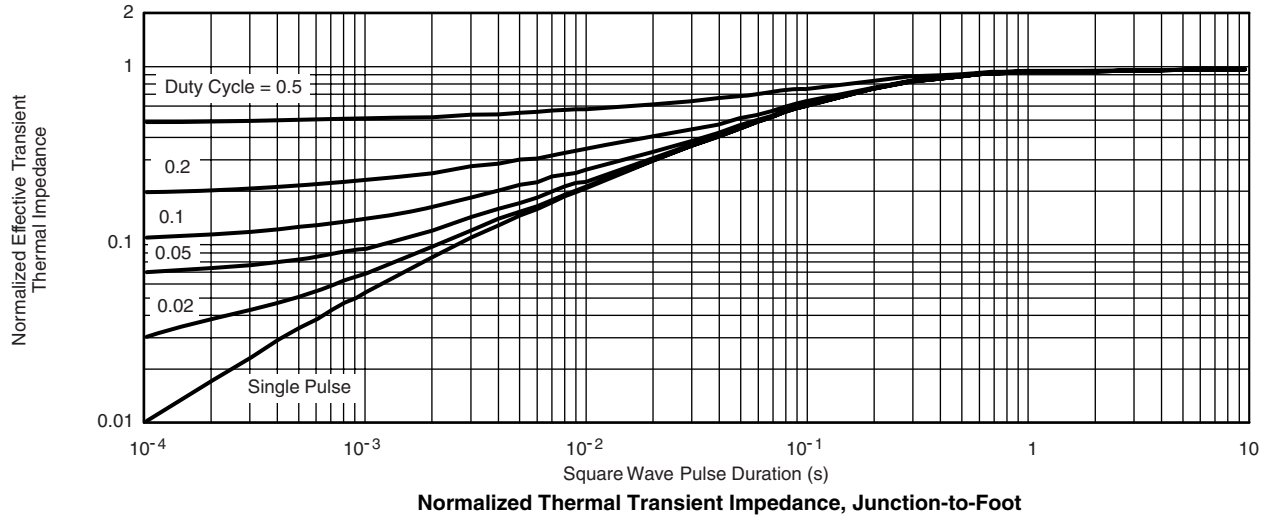
Safe Operating Area, Junction-to-Case



- Notes:
1. Duty Cycle, $D = \frac{t_1}{t_2}$
 2. Per Unit Base = $R_{thJA} = 130 \text{ } ^\circ\text{C/W}$
 3. $T_{JM} - T_A = P_{DM} Z_{thJA}^{(t)}$
 4. Surface Mounted

Normalized Thermal Transient Impedance, Junction-to-Ambient

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



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